

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	("5748179").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/05 16:36
L2	2	("20040207796").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/05 16:36
S2	403	349/152.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/20 15:17
S3	38	"349"/\$.ccls. and morishita.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 12:16
S4	283	349/152.ccls. and terminal	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/21 08:48
S5	27	349/152.ccls. and terminal near circuit	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 13:48
S6	247	S2 and transparent	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 16:26
S7	104	S2 and transparent near conductive	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 16:26

S8	116	S2 and transparent near conduct\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/19 16:37
S9	148	"349"/\$.ccls. and terminal same transparent adj conduct\$5 same resistance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/20 13:18
S17	46	"349"/\$.ccls. and "high resistance" same "low resistance" same conductive	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/20 15:12
S18	1576	"349"/\$.ccls. and circuit same adjacent same circuit	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/20 15:12
S19	200	"349"/\$.ccls. and circuit same adjacent near2 circuit	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/20 15:12
S21	31	"349"/\$.ccls. and circuit same "adjacent circuit"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/20 15:13
S22	320	349/152.ccls. and circuit	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/20 15:20
S23	2	("20040207796").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/22 09:49

S24	2	("5748179").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/20 17:00
S25	2	("6777973").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/21 09:27
S26	28	349/152.ccls. and external adj terminal same terminal	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 09:23
S27	39	"349"/\$.ccls. and conductive adj particles same (level equal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/21 10:12
S28	12	"349"/\$.ccls. and conductive adj (material film layer particle) same connect\$4 adj reliability	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/21 09:56
S29	95	"349"/\$.ccls. and conductive adj particles same (level equal even uneven)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/21 10:13
S30	7	"349"/\$.ccls. and high adj resistance adj conductive	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 09:40
S31	121	"349"/\$.ccls. and resistance adj conductive	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 09:45

S32	1483	"349"/\$.ccls. and conductive same (CR chromium)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 09:51
S33	223	"349"/\$.ccls. and conductive same (CR chromium) same terminal	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 09:56
S34	299	"349"/\$.ccls. and conductive same (CR chromium) same high	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 09:57
S35	2	"349"/\$.ccls. and (CR chromium) same high near resistance near conductive	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 09:58
S36	13	"349"/\$.ccls. and (CR chromium) same low near resistance near conductive	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 10:06
S37	1	"349"/\$.ccls. and (TI ta mo w ni titanium tantalum molybdenum tungsten nickel) same high near resistance near conductive	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 10:07
S38	107	"349"/\$.ccls. and (TI ta mo w ni titanium tantalum molybdenum tungsten nickel) same high near resistance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 10:15
S39	0	"349"/\$.ccls. and (TI ta mo w ni titanium tantalum molybdenum tungsten nickel) same high near resistance same connection near reliability	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 10:15

S40	3	"349"/\$.ccls. and (TI ta mo w ni titanium tantalum molybdenum tungsten nickel) same high near resistance same connection	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/22 10:16
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